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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Kulbinder K. Banger et al.

Serial No.: 10/698,118

Filing Date: October 31, 2003

Title: SINGLE-SOURCE PRECURSORS FOR TERNARY CHALCOPYRITE
MATERIALS, AND METHODS OF MAKING AND USING THE SAME

Docket No.: 35089US1

INFORMATION DISCLOSURE STATEMENT

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Respectfully submitted,
PEARNE & GORDON LLP

By: 

Steven J. Solomon, Reg. No.: 48719

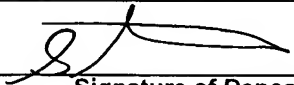
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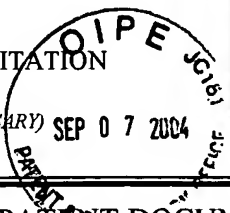
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INFORMATION DISCLOSURE CITATION BY APPLICANT (USE SEVERAL SHEETS IF NECESSARY) Page 1 of 1				APPLICANT: Kulbinder K. Banger et al.	
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U.S. PATENT DOCUMENTS							
Examiner Initial		Document No.	Date	Name	Class	Subclass	Filing Date If Appropriate
	A						
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FOREIGN PATENT DOCUMENTS							
		Document No.	Date	Country	Class	Subclass	Translation
	D						

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)	
E	Tarrant, D., et al., "I-III-VI ₂ Multinary Solar Cells Based on CuInSe ₂ ", <i>Proc. 23rd IEEE Photovoltaic Specialist Conference</i> , 1993, pp. 372-378.
F	Shibata, J., et al., "Transmission Electron Microscopic Studies of LiNb _{0.5} Ta _{0.5} O ₃ Films Deposited on Sapphire Substrates by Thermal Plasma Spray CVD (Microstructure of LiNb _{0.5} Ta _{0.5} O ₃ Films Deposited by Thermal Plasma Spray CVD)", <i>Materials Transactions</i> , 2002, 43(7), pp. 1517-1524
G	Hollingsworth, J.A., et al., "Spray Chemical Vapor Deposition of CuInS ₂ Thin Films for Application in Solar Cell Devices", <i>Mat. Res. Soc. Symp. Proc.</i> , 1998, vol. 495, pp. 171-176.
H	Jin, M. H., et al., "Thin Film CuInS ₂ Prepared by Spray Pyrolysis with Single-Source Precursors", <i>Conference Record of the 29th IEEE Photovoltaic Specialists Conference</i> , 2002, pp. 672-675.
I	Harris, J.D., et al., "Using Single Source Precursors and Spray Chemical Vapor Deposition to Grow Thin-Film CuInS ₂ ", <i>Proc. of the 28th IEEE Photovoltaic Specialists Conference</i> , 2000, pp. 563-566.
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